SCS205KG

SiC Schottky Barrier Diode

Datasheet

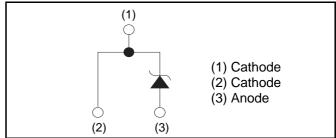
V_R	1200V
I _F	5A
Q_{C}	17nC

Outline TO-220AC (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

_	or dottaging oppositioning				
	Туре	Packaging	Tube		
		Reel size (mm)	-		
		Tape width (mm)	-		
		Basic ordering unit (pcs)	50		
		Packing code	С		
		Marking	SCS205KG		

•Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	1200	V
Reverse voltage (DC)		V_{R}	1200	V
Continuous forward	d current (T _c = 150°C)	l _F	5	Α
Surge non-	PW=10ms sinusoidal, T _j =25°C		23	Α
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	17	Α
	PW=10μs square, T _j =25°C		80	А
Repetitive peak forward current		I _{FRM}	27 *1	А
PW=10ms, T _j =25°C		۲.2.	2.5	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	1.4	A ² s
Total power dissipation		P_{D}	88 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	nbol Conditions -	Values			Unit
Parameter	Symbol		Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.1mA	1200	-	-	V
	V _F	I _F =5A,T _j =25°C	-	1.4	1.6	V
Forward voltage		I _F =5A,T _j =150°C	-	1.8	-	V
		I _F =5A,T _j =175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,T _j =25°C	-	5	100	μА
		V _R =1200V,T _j =150°C	-	40	-	μА
		V _R =1200V,T _j =175°C	-	65	-	μА
Total capacitance	С	V _R =1V,f=1MHz	-	260	-	pF
		V _R =800V,f=1MHz	-	21	-	pF
Total capacitive charge	Q _C	V _R =800V,di/dt=500A/μs	-	17	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	15	-	ns

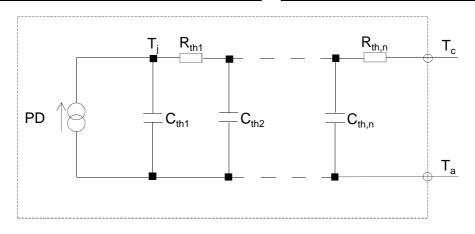
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.5	1.7	°C/W

● Typical Transient Thermal Characteristics

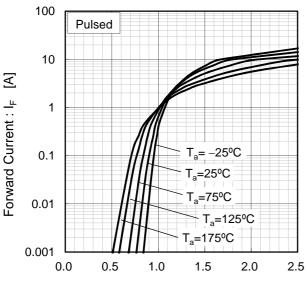
	T	
Symbol	Value	Unit
R _{th1}	3.06E-01	
R _{th2}	9.33E-01	K/W
R _{th3}	2.62E-01	

Symbol	Value	Unit
C _{th1}	2.49E-03	
C _{th2}	4.92E-03	Ws/K
C _{th3}	9.57E-02	



•Electrical characteristic curves

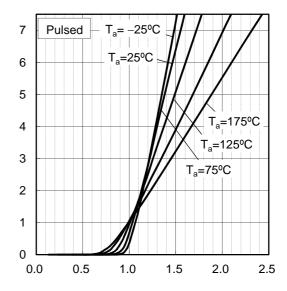
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

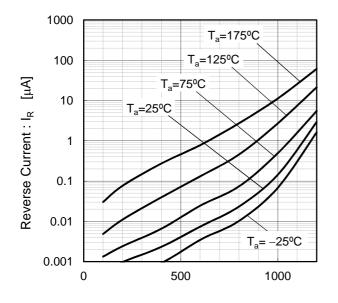
Fig.2 V_F - I_F Characteristics

Forward Current : IF [A]



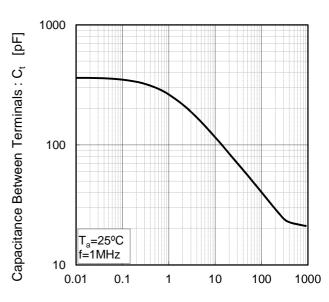
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

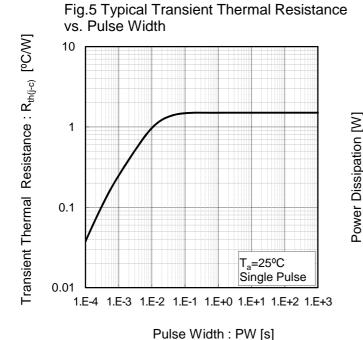
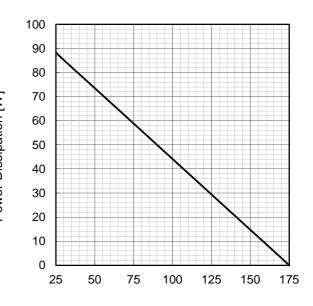
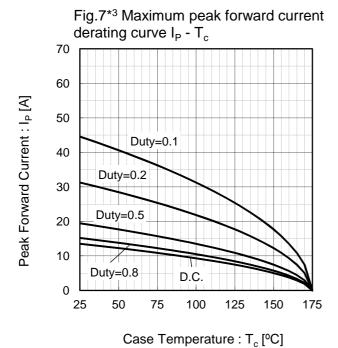


Fig.6 Power Dissipation



Case Temperature : T_c [°C]



*3 Based on max Vf, max R_{th(j-c)}

excluding D.C. curve.

Valid for switching of above 10kHz,

derating curve I_P - T_c (Not guaranteed) Duty=0.1 60 Peak Forward Current : Ip [A]

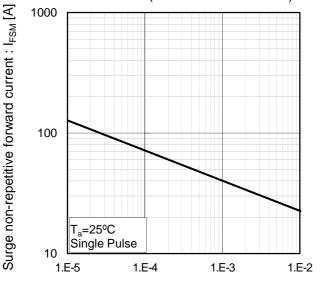
Fig.8*4 Typical peak forward current

50 Duty=0.2 40 Duty=0.5 30 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

> Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

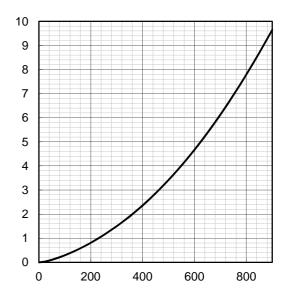
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

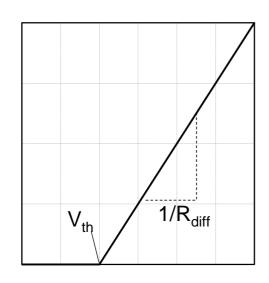


Capacitance stored energy : $\mathsf{E}_{_{\mathrm{C}}}[\mu \mathsf{J}]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.93E-01	V
a ₁	-1.27E-03	V/°C
b ₀	7.30E-02	Ω
b ₁	4.12E-04	Ω/°C
b ₂	2.66E-06	$\Omega/^{\circ}C^{2}$

 T_{j} in °C; -55 °C < T_{j} < °C ; I_{F} < 10 A

Forward Current: IF

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